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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/081,842	02/25/2002	Tatsuya Kunisato	57810-031 . 4343		
. 75	90 07/01/2003			•	
McDERMOTT, WILL & EMERY 600 13th Street, N.W. Washington, DC 20005-3096			EXAMINER		
			LAM, CATHY FONG FONG		
			ART UNIT	PAPER NUMBER	
		•	1775		
			DATE MAILED: 07/01/2003		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Application No. Applicant(s)		- Ma			
Office Action Summary		10/081,842 KUNISATO ET AL.		<b></b>				
		Examiner	· · · · · · · · · · · · · · · · · · ·	Art Unit	<del>-</del>			
		Cathy Lam		1775				
	Th MAILING DATE of this communication appears on the cov r sh t with the correspondence address Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).  - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).  Status								
1) 🗌	Responsive to communication(s) filed on	·						
2a)□	This action is <b>FINAL</b> . 2b)⊠ Th	nis action is non-f	nal.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.  Disposition of Claims								
4)⊠ Claim(s) <u>1-23</u> is/are pending in the application.								
4a) Of the above claim(s) <u>12-23</u> is/are withdrawn from consideration.								
5) Claim(s) is/are allowed.								
6)⊠ Claim(s) <u>1-11</u> is/are rejected.								
7) Claim(s) is/are objected to.								
8) Claim(s) are subject to restriction and/or election requirement.								
	on Papers							
<u></u>	The specification is objected to by the Examine							
10)⊠ The drawing(s) filed on <u>25 February 2002</u> is/are: a)⊠ accepted or b)□ objected to by the Examiner.								
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).								
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.								
If approved, corrected drawings are required in reply to this Office action.								
12) The oath or declaration is objected to by the Examiner.								
Priority under 35 U.S.C. §§ 119 and 120								
13)⊠ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).								
a)[	a)⊠ All b)□ Some * c)□ None of:							
	1.⊠ Certified copies of the priority documents have been received.							
2. Certified copies of the priority documents have been received in Application No								
3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.								
14) 🗌 A	cknowledgment is made of a claim for domest	ic priority under 3	5 U.S.C. § 119(	e) (to a provisiona	I application).			
a	)  The translation of the foreign language pro- Acknowledgment is made of a claim for domest	ovisional applicati	on has been rec	eived.	,			
Attachment		- •						
2) D Notice	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449) Paper No(s) <u>5</u>	4) 5) 6) 1		/ (PTO-413) Paper No Patent Application (PT				
U.S. Patent and Tr PTO-326 (Re	0.4.04)	ction Summary		Part of Paper No. 6	•			

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- 1. Restriction to one of the following inventions is required under 35 U.S.C. 121:
  - I. Claims 1-11, drawn to a nitride based semiconductor element, classified in class 428, subclass 627.
  - II. Claims 12-23, drawn to a method of making a nitride based semiconductor element, classified in class 438, subclass 604.

The inventions are distinct, each from the other because of the following reasons:

- 2. Inventions II and I are related as process of making and product made. The inventions are distinct if either or both of the following can be shown: (1) that the process as claimed can be used to make other and materially different product or (2) that the product as claimed can be made by another and materially different process (MPEP § 806.05(f)). In the instant case the product as claimed can be made by a different process such as by using sol gel process to form the nitride based semiconductor layer onto the substrate. The process as claimed can be used to make a different product such as a three dimensional decorative article.
- 3. Because these inventions are distinct for the reasons given above and have acquired a separate status in the art as shown by their different classification, restriction for examination purposes as indicated is proper.
- 4. During a telephone conversation with Atty: Arthur Steiner on 12<sup>th</sup> Jun 2003, applicant's representative advised that a previous provisional election was made back in December 2002, as to election without traverse to prosecute the invention of group I, claims 1-11. Affirmation of this election must be made by applicant in replying to this

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Office action. Claims 12-23 are withdrawn from further consideration by the examiner, 37 CFR 1.142(b), as being drawn to a non-elected invention.

5. Applicant is reminded that upon the cancellation of claims to a non-elected invention, the inventorship must be amended in compliance with 37 CFR 1.48(b) if one or more of the currently named inventors is no longer an inventor of at least one claim remaining in the application: Any amendment of inventorship must be accompanied by a request under 37 CFR 1.48(b) and by the fee required under 37 CFR 1.17(i).

#### Specification

6. Applicant is reminded of the proper language and format for an abstract of the disclosure.

The abstract should be in narrative form and generally limited to a single paragraph on a separate sheet within the range of 50 to 150 words. It is important that the abstract not exceed 150 words in length since the space provided for the abstract on the computer tape used by the printer is limited. The form and legal phraseology often used in patent claims, such as "means" and "said," should be avoided. The abstract should describe the disclosure sufficiently to assist readers in deciding whether there is a need for consulting the full patent text for details.

The language should be clear and concise and should not repeat information given in the title. It should avoid using phrases which can be implied, such as, "The disclosure concerns," "The disclosure defined by this invention," "The disclosure describes," etc.

## Claim Rejections - 35 USC § 112

7. Claims 3, 8 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

It is vague and indefinite as to whether or not "facets" are formed from the nitride based semiconductor layer in claim 1.

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In claim 8, the phrase "said inverse-trapezoidal convex portions" lacks antecedent basis.

### Claim Rejections - 35 USC § 102

8. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 9. Claims 1-11 are rejected under 35 U.S.C. 102(e) as being anticipated by Kunisto et al (US 2002/0038870 A1).

The applied reference has a common assignee with the instant application. Based upon the earlier effective U.S. filing date of the reference, it constitutes prior art under 35 U.S.C. 102(e). This rejection under 35 U.S.C. 102(e) might be overcome either by a showing under 37 CFR 1.132 that any invention disclosed but not claimed in the reference was derived from the inventor of this application and is thus not the invention "by another," or by an appropriate showing under 37 CFR 1.131.

Kunisato discloses a nitride based semiconductor comprised of a substrate (or an underlayer) (1), a mask (2), a buffer layer, and a nitride based semiconductor layer (4); all in the named order (Figs 4, 5).

The nitride based semiconductor layer (4) has a facet structure (paragraph 0049 L 8-10 & Fig. 3).

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Kunisato also teaches that the mask (2) can be an inverse trapezoidal shape or has side portions protruding sideward (paragraph 0067 & Figs 7 & 8). The mask can also be a two layer structure that comprised two different material layers (claim 16 & Fig. 9). Kunisato also states in claim 21 that the substrate can comprised a trapezoidal shape.

A further nitride based semiconductor element layer (5) is formed onto the nitride based semiconductor layer and having an element region (Fig. 5 & paragraph 0058).

### **Double Patenting**

10. Claims 1-2 and 4-9 are provisionally rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 12 and 18-21 of copending Application No. 09/968886. Although the conflicting claims are not identical, they are not patentably distinct from each other because they are structurally and materially the same.

This is a <u>provisional</u> obviousness-type double patenting rejection because the conflicting claims have not in fact been patented.

11. The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970);and, *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Cathy Lam whose telephone number is (703) 308-2418. The examiner can normally be reached on 9am-6pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Deborah Jones can be reached on (703) 308-3822. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 872-9604 for regular communications and (703) 872-9311 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0661.

**Primary Examiner** 

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June 27, 2003